Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal and ceramic **Overall Length:** 0.292 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 amperes all primaries preset **Power Rating Per Characteristic:** 18.0 watts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 175.0 degrees celsius junction **Thread Series Designator:** Unc **Terminal Type And Quantity:** 2 ribbon Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0